

Vishay Semiconductors

Small Signal Fast Switching Diodes

Features

- Silicon epitaxial planar diodes
- Electrical data identical with the devices 1N4148 and 1N4448 respectively
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition







Applications

· Extreme fast switches

Mechanical Data

Case: MiniMELF SOD-80
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/2.5K per 7" reel (8 mm tape), 12.5K/box

Parts Table

Part	Type differentiation	Ordering code	Marking code	Remarks
LL4148-M	$V_{RRM} = 100 \text{ V},$ $V_{F} = \text{max. } 1000 \text{ mV at } I_{F} = 50 \text{ mA}$	LL4148-M-08 or LL4148-M-18	-	Tape and reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	100	V
Reverse voltage		V_R	75	V
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α
Repetitive peak forward current		I _{FRM}	500	mA
Forward continuous current		I _F	300	mA
Average forward current	V _R = 0	I _{FAV}	150	mA
Power dissipation		P _{tot}	500 ¹⁾	mW

Note

Rev. 1.1, 01-Sep-10

¹⁾ Valid provided that electrodes are kept at ambient temperature

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Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Thermal resistance junction to ambient air		R _{thJA}	300 ¹⁾	K/W	
Junction temperature		T _j	175	°C	
Storage temperature range		T _{stg}	- 65 to + 175	°C	

Note

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 50 mA	V _F		860	1000	mV
	V _R = 20 V	I _R			25	nA
Reverse current	$V_{R} = 20 \text{ V}, T_{j} = 150 ^{\circ}\text{C}$	I _R			50	μΑ
	V _R = 75 V	I _R			5	μΑ
Breakdown voltage	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V _(BR)	100			V
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			4	pF
Dougrap recovery time	$I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$	t _{rr}			8	ns
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			4	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

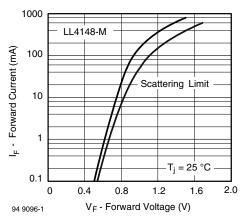


Figure 1. Forward Current vs. Forward Voltage

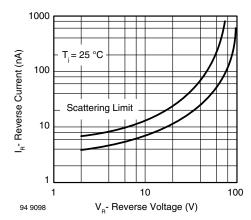


Figure 2. Reverse Current vs. Reverse Voltage

¹⁾ Valid provided that electrodes are kept at ambient temperature



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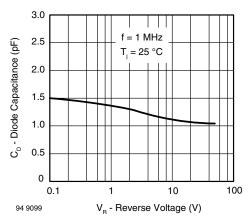
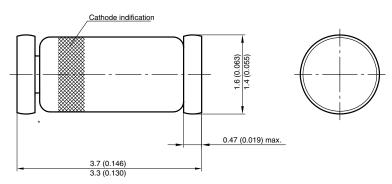
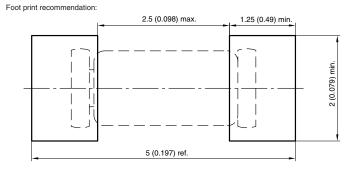


Figure 3. Diode Capacitance vs. Reverse Voltage

Package Dimensions in millimeters (inches): MiniMELF SOD-80



* The gap between plug and glass can be either on cathode or anode side



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